

状态	型号	容量	NAND 工艺	尺寸 (mm)	封装球数	OPS性能	Performance (MB/s) Seq Read Seq Write	供电电压	接口电压	功耗电流	Deep mode 电流 (nA)	支持平台	备注
MP Now	KLM4G1FE3B-B001018	4GB	21nm MLC	11.5*13*1.0	153	Class50	44	8.2. 7V~3.6V	1.7V~1.95V	50mA	0uA (In auto power saving mode)	TBD	32Gb MLC x 1 VFX U
MP Now	KLM8G2FE3B-B001018	8GB	21nm MLC	11.5*13*1.0	153	Class100	44	14.2. 7V~3.6V	1.7V~1.95V	100mA	0uA (In auto power saving mode)	TBD	32Gb MLC x 2
MP Now	KLMAG2GE4A-A001023	16GB	21nm MLC	12*16*1.0	169	Class400	75	43.2. 7V~3.6V	1.7V~1.95V	100mA	0uA (In auto power saving mode)	TBD	64Gb MLC x 2 VHX
MP Now	KLM8G4GE4A-A001023	32GB	21nm MLC	12*16*1.0	169	Class400	80	35.2. 7V~3.6V	1.7V~1.95V	100mA	0uA (In auto power saving mode)	TBD	64Gb MLC x 4 VHX
MP Now	KLMCG8GE4A-A001023	64GB	21nm MLC	12*16*1.2	169	Class400	80	35.2. 7V~3.6V	1.7V~1.95V	100mA	0uA (In auto power saving mode)	TBD	64Gb MLC x 8 VHX
MP Now	KLM8G2FE2B-B001	8GB	21nm MLC	11.5*13*1.0	153	Class700	71	21.2. 7V~3.6V	1.7V~1.95V	100mA	0uA (In auto power saving mode)	TBD	32Gb MLC x 2 VHX
MP Now	KLMAG4FE4B-B001003	16GB	21nm MLC	11.5*13*1.0	153	Class700	75	43.2. 7V~3.6V	1.7V~1.95V	200mA	0uA (In auto power saving mode)	TBD	32Gb MLC x 4 VHX
MP Now	KLM8G8FE4B-B001003	32GB	21nm MLC	11.5*13*1.0	153	Class700	75	43.2. 7V~3.6V	1.7V~1.95V	200mA	0uA (In auto power saving mode)	TBD	32Gb MLC x 8 VHX
CS Now	KLMAG2GE2A-A001004	16GB	21nm MLC	12*16*1.0	169	Class150	71	42.2. 7V~3.6V	1.7V~1.95V	100mA	0uA (In auto power saving mode)	TBD	64Gb MLC x 2 VHX2
CS Now	KLM8G4GE2A-A001004	32GB	21nm MLC	12*16*1.0	169	Class150	71	50.2. 7V~3.6V	1.7V~1.95V	200mA	0uA (In auto power saving mode)	TBD	64Gb MLC x 4 VHX2
CS Now	KLMCG8GE2A-A001004	64GB	21nm MLC	12*16*1.2	169	Class150	71	50.2. 7V~3.6V	1.7V~1.95V	200mA	0uA (In auto power saving mode)	TBD	64Gb MLC x 8 VHX2
CS 9/E	KLM8G6GE2A-A001000	128GB	21nm MLC	12*16*1.6	169	Class150	71	50.2. 7V~3.6V	1.7V~1.95V	200mA	0uA (In auto power saving mode)	TBD	64Gb MLC x 16 VHX2
EMMC5.0	KLM4G1FEAC-B031	4GB	19nm MLC	11.5*13*1.0	153	Class700	120	14.2. 7V~3.6V	1.7V~1.95V	80mA	0uA (In auto power saving mode)	TBD	32Gb MLC x 1
EMMC4.5	KLM8G1GEAC-B031	8GB	19nm MLC	11.5*13*1.0	153	Class700	120	18.2. 7V~3.6V	1.7V~1.95V	80mA	0uA (In auto power saving mode)	TBD	64Gb MLC x 1 VMX
EMMC4.5	KLMAG2GEAC-B001001	16GB	19nm MLC	11.5*13*1.0	153	Class200	150	40.2. 7V~3.6V	1.7V~1.95V	130mA	0uA (In auto power saving mode)	TBD	64Gb MLC x 2 VMX
EMMC4.5	KLM8G4GEAC-B001001	32GB	19nm MLC	11.5*13*1.0	153	Class200	150	50.2. 7V~3.6V	1.7V~1.95V	230mA	0uA (In auto power saving mode)	TBD	64Gb MLC x 4 VMX
EMMC4.5	KLMCG8GEAC-B001	64GB	19nm MLC	11.5*13*1.0	153	Class200	150	50.2. 7V~3.6V	1.7V~1.95V	230mA	0uA (In auto power saving mode)	TBD	64Gb MLC x 8 VMX
EMMC4.5	KLM8G6GEAC-B001	128GB	19nm MLC	11.5*13*1.0	153	Class200	100	50.2. 7V~3.6V	1.7V~1.95V	230mA	0uA (In auto power saving mode)	TBD	64Gb MLC x 16 VMX
EMMC5.0	KLM8G1GEAC-B031	8GB	19nm MLC	11.5*13*1.0	153	Class700	175	18.2. 7V~3.6V	1.7V~1.95V	80mA	0uA (In auto power saving mode)	TBD	
EMMC5.0	KLMAG2GEAC-B031	16GB	19nm MLC	11.5*13*1.0	153	Class200	220	40.2. 7V~3.6V	1.7V~1.95V	130mA	0uA (In auto power saving mode)	TBD	
EMMC5.0	KLM8G4GEAC-B031	32GB	19nm MLC	11.5*13*1.0	153	Class200	250	50.2. 7V~3.6V	1.7V~1.95V	230mA	0uA (In auto power saving mode)	TBD	
EMMC5.0	KLMCG8GEAC-B031	64GB	19nm MLC	11.5*13*1.0	153	Class200	250	50.2. 7V~3.6V	1.7V~1.95V	230mA	0uA (In auto power saving mode)	TBD	
MP Now	KLM4G1FE4C-B001005	4GB	21nm TLC	11.5*13*1.0	153	Class100	77	7.2. 7V~3.6V	1.7V~1.95V	50mA	0uA (In auto power saving mode)	TBD	32Gb MLC x 1 VHX
MP Now	KLM8G1WE4A-A001005	8GB	21nm TLC	12*16*1.0	169	Class100	77	12.2. 7V~3.6V	1.7V~1.95V	50mA	0uA (In auto power saving mode)	TBD	32Gb MLC x 2 VHX
MP Now	KLMAG2WE4A-A001003	16GB	21nm TLC	12*16*1.0	169	Class400	77	11.2. 7V~3.6V	1.7V~1.95V	100mA	0uA (In auto power saving mode)	TBD	64Gb MLC x 2 VHX
MP Now	KLM8G4WE4A-A001002	32GB	21nm TLC	12*16*1.0	169	Class400	77	20.2. 7V~3.6V	1.7V~1.95V	200mA	0uA (In auto power saving mode)	TBD	64Gb MLC x 4 VHX
MP Now	KLMCG8WE4A-A001004	64GB	21nm TLC	12*16*1.2	169	Class400	77	20.2. 7V~3.6V	1.7V~1.95V	200mA	0uA (In auto power saving mode)	TBD	64Gb MLC x 8 VHX
EMMC5.0	KLM4G1VEMD-B031	4GB	19nm TLC	11.5*13*0.8	153	Class200	90	6.2. 7V~3.6V	1.7V~1.95V	80mA	0uA (In auto power saving mode)	TBD	32Gb TLC x 1
EMMC5.0	KLM8G1VEMB-B031	8GB	19nm TLC	11.5*13*0.8	153	Class700	100	6.2. 7V~3.6V	1.7V~1.95V	80mA	0uA (In auto power saving mode)	TBD	64Gb TLC X1
EMMC5.0	KLMAG2VEMB-B031	16GB	19nm TLC	11.5*13*0.8	153	Class700	170	11.2. 7V~3.6V	1.7V~1.95V	130mA	0uA (In auto power saving mode)	TBD	64Gb TLC X2
EMMC5.0	KLM8G4VEMB-B031	32GB	19nm TLC	11.5*13*1.0	153	Class150	220	50.2. 7V~3.6V	1.7V~1.95V	200mA	0uA (In auto power saving mode)	TBD	64Gb TLC X4
EMMC5.0	KLMCG8VEMB-B031	64GB	19nm TLC	11.5*13*1.0	153	Class150	220	50.2. 7V~3.6V	1.7V~1.95V	200mA	0uA (In auto power saving mode)	TBD	64Gb TLC X8
EMMC5.0	KLM8G1VEPD-B031	8GB	16nm TLC	11.5*13*0.8	153	Class500	130	7.2. 7V~3.6V	1.7V~1.95V	80mA	0uA (In auto power saving mode)	TBD	64Gb TLC X1
EMMC5.0	KLM8G2VEPD-B031	16GB	16nm TLC	11.5*13*0.8	153	Class800	150	12.2. 7V~3.6V	1.7V~1.95V	130mA	0uA (In auto power saving mode)	TBD	64Gb TLC X2
EMMC5.0	KLM8G4VEPD-B031	32GB	16nm TLC	11.5*13*1.0	153		260	46.2. 7V~3.6V	1.7V~1.95V	200mA	0uA (In auto power saving mode)	70uA @25摄氏度 235uA @40摄氏度	
EMMC5.0	KLMCG8VEPD-B031	64GB	16nm TLC	11.5*13*1.0	153		260	46.2. 7V~3.6V	1.7V~1.95V	200mA	0uA (In auto power saving mode)	130uA @25摄氏度 435uA @40摄氏度	
EMMC5.0	KLM8G4VFPD-B031	128GB	16nm TLC	11.5*13*1.4	153								
EMMC5.0	KLM4G1FEPD-B031	4GB	16nm MLC	11*10*0.8	153		120	15.2. 7V~3.6V	1.7V~1.95V	80mA	0uA (In auto power saving mode)		32Gb MLC X1
EMMC5.0	KLM8G1GEND-B031	8GB	16nm MLC	11.5*13*0.8	153	Class250	160	25.2. 7V~3.6V	1.7V~1.95V	50mA	0uA (In auto power saving mode)		64Gb MLC X1
EMMC5.0	KLMAG2GEND-B031	16GB	16nm MLC	11.5*13*0.8	153	Class600	230	50.2. 7V~3.6V	1.7V~1.95V	100mA	0uA (In auto power saving mode)		64Gb MLC X2
EMMC5.0	KLM8G4GEND-B031	32GB	16nm MLC	11.5*13*1.0	153	Class1200	250	100.2. 7V~3.6V	1.7V~1.95V	200mA	0uA (In auto power saving mode)		64Gb MLC X4
EMMC5.0	KLMCG8GEND-B031	64GB	16nm MLC	11.5*13*1.0	153	Class1200	250	100.2. 7V~3.6V	1.7V~1.95V	200mA	0uA (In auto power saving mode)		64Gb MLC X8
EMMC5.0	KLM8G1GESD-B03x	8GB	16nm MLC	11.5*13*0.8	153		160	25.2. 7V~3.6V	1.7V~1.95V	50mA	0uA (In auto power saving mode)		64Gb MLC X1
EMMC5.0	KLMAG2GESD-B03x	16GB	16nm MLC	11.5*13*0.8	153		230	50.2. 7V~3.6V	1.7V~1.95V	100mA	0uA (In auto power saving mode)		64Gb MLC X2
EMMC5.0	KLM8G4GESD-B03x	32GB	16nm MLC	11.5*13*0.8	153		250	100.2. 7V~3.6V	1.7V~1.95V	200mA	0uA (In auto power saving mode)		64Gb MLC X4
EMMC5.0	KLMCG8GESD-B03x	64GB	16nm MLC	11.5*13*1.0	153		250	100.2. 7V~3.6V	1.7V~1.95V	200mA	0uA (In auto power saving mode)		64Gb MLC X8
EMMC5.1	KLM8G1GEM-B041	8GB	14nm MLC	11.5*13*0.8	153		185	40.2. 7V~3.6V	1.7V~1.95V	80mA	0uA (In auto power saving mode)		64Gb MLC X1
EMMC5.1	KLMAG1TENB-B041	16GB	14nm MLC	11.5*13*0.8	153		285	40.2. 7V~3.6V	1.7V~1.95V	50mA	0uA (In auto power saving mode)		128Gb MLC X1
EMMC5.1	KLM8G2TENB-B041	32GB	14nm MLC	11.5*13*1.0	153		310	70.2. 7V~3.6V	1.7V~1.95V	100mA	0uA (In auto power saving mode)		128Gb MLC X2
EMMC5.1	KLMCG4TENB-B041	64GB	14nm MLC	11.5*13*1.0	153		310	140.2. 7V~3.6V	1.7V~1.95V	200mA	0uA (In auto power saving mode)		128Gb MLC X4
EMMC5.1	KLMCG2KETM-B041	64GB	48 layer	11.5*13*1.0	153		330	200.2. 7V~3.6V	1.7V~1.95V	200mA	0uA (In auto power saving mode)		256Gb MLC X2
EMMC5.1	KLM8G8TENB-B041	128GB	14nm MLC	11.5*13*1.2	153		310	140.2. 7V~3.6V	1.7V~1.95V	200mA	0uA (In auto power saving mode)		128Gb MLC X8
EMMC5.1	KLMCG4VERF-B041	64GB	14nm TLC		153								
EMMC5.1	KLM8G8VERF-B041	128GB	14nm TLC		153								
EMMC5.1	KLM4G1FETE-B041	4GB	14nm next	11*10*0.8	153		300	19.2. 7V~3.6V	1.7V~1.95V	50mA	0uA (In auto power saving mode)		32Gb MLC X1
EMMC5.1	KLM8G1GETF-B041	8GB	14nm next	11.5*13*0.8	153		330	50.2. 7V~3.6V	1.7V~1.95V	50mA	0uA (In auto power saving mode)		64Gb MLC X1
EMMC5.1	KLMAG1TETD-B041	16GB	14nm next	11.5*13*0.8	153		330	50.2. 7V~3.6V	1.7V~1.95V	50mA	0uA (In auto power saving mode)		128Gb MLC X1
EMMC5.1	KLM8G2TETD-B041	32GB	14nm next	11.5*13*0.8	153		330	100.2. 7V~3.6V	1.7V~1.95V	100mA	0uA (In auto power saving mode)		128Gb MLC X2
EMMC5.1	KLMCG4TETD-B041	64GB	14nm next	11.5*13*1.0	153		330	200.2. 7V~3.6V	1.7V~1.95V	200mA	0uA (In auto power saving mode)		128Gb MLC X4
EMMC5.1	KLM8G8TETD-B041	128GB	48 layer	11.5*13*1.0	153		320	150.2. 7V~3.6V	1.7V~1.95V	200mA	0uA (In auto power saving mode)		256Gb TLC X4
EMMC5.1	KLM8G8TETD-B041	128GB	48 layer	11.5*13*1.0	153		320	150.2. 7V~3.6V	1.7V~1.95V	200mA	0uA (In auto power saving mode)		256Gb TLC X8
EMMC5.1	KLMCG2KCTA-B041	64GB	64 layer	11.5*13*0.8	153		330	200.2. 7V~3.6V	1.7V~1.95V	200mA	0uA (In auto power saving mode)		256Gb MLC X2
EMMC5.1	KLM8G4UCTA-B041	128GB	64 layer	11.5*13*1.0	153		325	200.2. 7V~3.6V	1.7V~1.95V	200mA	0uA (In auto power saving mode)		256Gb TLC X4
EMMC5.1	KLM8G8UCTA-B041	256GB	64 layer	11.5*13*1.0	153		325	200.2. 7V~3.6V	1.7V~1.95V	200mA	0uA (In auto power saving mode)		256Gb TLC X8